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The photocathodic properties of a Fe_2O_3 wrapped $CuFeO_2$ layer on ITO glass for water splitting



CHEMICAL

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Keywords: CuFeO ₂ Photoelectrochemical property Water splitting	A Fe_2O_3 wrapped $CuFeO_2$ layer structure was fabricated on ITO glass by electrophoretic deposition and sol-gel methods at 400 °C. Such low fabrication temperature avoids the damage of ITO glass's transparency and conductivity. The FeCl ₃ gel penetrated through the $CuFeO_2$ layer enhanced the connection and conductivity between $CuFeO_2$ particles and $CuFeO_2/ITO$ glass interface. Pt particles were decorated on the surface by a photoreduction method to improve the PEC performance. The inserted Fe_2O_3 thin layer between the $CuFeO_2$ layer and Pt particles also worked as a buffer layer, which removed the upward barrier at the interface and improved the PEC activity.

1. Introduction

Semiconductor photoelectrodes have attracted much attention in relation to renewable energy technology for harvesting and conversion of solar light to hydrogen by water splitting reactions. Metal oxides with long-term stability in aqueous electrolytes and abundant reserves have been well-studied as the most attractive candidates for semiconductor photoelectrodes [1]. However, most of the metal oxide photoelectrodes are *n*-type with conduction band edges more positive than the redox potential of hydrogen reduction. They can only be used as photoanodes and are not suitable for hydrogen production. Research on cost-effective p-type oxide-based photocathodes is quite sparse. Recently, the research interest on p-type CuFeO₂ is growing as it possesses high stability in aqueous environment, visible light absorption and suitable band structure, which suggests the capability to develop a highly efficient photocathode for the reduction of water to hydrogen. As the most attractive front photoelectrode materials, intensive efforts have been devoted to developing CuFeO₂ photoelectrode in multipleabsorber-based tandem photoelectrodes to achieve high solar-to-hydrogen (STH) efficiency [2]. A few different fabrication methods have been reported to produce CuFeO2 photocatalyst, such as electrochemical deposition [3], solid-state synthesis [4], sol-gel method [5] and microwave treatment was also used [6]. In order to achieve good conductivity between the CuFeO₂ film photoelectrode and substrate, annealing is essential, with the annealing temperature usually between 700 °C and 1000 °C, lasting for a couple of days [2,7,8]. For the most commonly used transparent conductive substrates, like ITO or FTO glass, such high temperature is harmful for their transparency and conductivity. It was reported that the CuFeO₂ film photoelectrodes can be destroyed resulting from the breakdown of FTO glass substrate above 700 °C annealing treatment [9].

In this study, we try to fabricate a Fe₂O₃ wrapped CuFeO₂ film photoelectrode on ITO glass substrate by alternately using electrophoretic deposition (EPD) and sol-gel method at 400 °C. Fe₂O₃ was used to enhance the connection of CuFeO₂ particles and the conductivity between CuFeO₂ particle layer and ITO glass without bring in impurity elements. The Fe₂O₃ also acted as a buffer layer on top of CuFeO₂ particle layer and formed a smooth surface for Pt catalyst particle decoration. This inserted Fe₂O₃ buffer layer between CuFeO₂ and Pt particles inhibited the formation of CuFeO₂/Pt Schottky upward barrier and made the photo-generated carriers separate efficiently in the electrode. A photocathodic current density of $-274 \,\mu\text{A/cm}^2$ at 0 V vs. Ag/AgCl and an onset potential of 0.87 V vs. Ag/AgCl were obtained under 100 mW/cm² Xe lamp illumination. The photocathode shows high stability in aqueous electrolyte after 5 h PEC continuous testing and high faradic efficiency for hydrogen production.

2. Experimental

The Pt decorated Fe₂O₃ wrapped CuFeO₂ photoelectrode was

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Fig. 1. Cross-sectional SEM images of (a) CuFeO2 deposited on ITO glass substrate by EPD method (CFO-0), (b) CFO-1, (c) CFO-3 and (d) CFO-5.

fabricated by alternately using EPD and sol-gel methods. In a typical procedure, the CuFeO₂ powder was firstly prepared by calcination method at 1100 °C under Ar atmosphere as described in reference [8], and then deposited on ITO glass substrate by EPD method. The CuFeO₂ particles layer was then wrapped intimately by spin-coating FeCl₃ gel on the top 5 times and annealed at 400 °C for 2 h in air. Finally, the Pt catalyst particles were deposited on the surface by photochemical reduction (for more detailed procedures, see Supporting Information).

3. Results and discussion

Fig. 1a shows the loosely stacked CuFeO₂ particle layer deposited on ITO glass by an EPD method. Since the CuFeO₂ particles were only attracted to each other by weak electrical field forces and the 400 °C annealing process was not sufficient for re-crystallization of CuFeO₂ particles, the porous structure and irregular particle sizes we can see is reasonable. In addition, the CuFeO2 particle layer also loosely contacted with the ITO glass substrate. An obvious gap was formed at the interface of CuFeO₂ particle layer and ITO glass. This poor connection among CuFeO₂ particles and poor conductivity between CuFeO₂ layer and ITO glass leads to the fragility of the photoelectrode in aqueous electrolyte. After one time of FeCl₃ gel spin-coating and annealing, the Fe₂O₃ filled in the voids among CuFeO₂ particles partially, as demonstrated in Fig. 1b. With the increasing of spin-coating times, the FeCl₃ gel permeation improved the connection among CuFeO₂ particles obviously and no obvious gap can be observed at the CuFeO₂ layer and ITO glass, as we can see in Fig. 1c and d.

The FeCl₃ gel spin-coating and annealing process can also change the surface morphology of samples. The CFO-0 sample shows a porous and uninformed surface morphology as we can see in Fig. 2a. The interparticle connection happens due to the FeCl₃ gel penetrating from the top of CuFeO₂ particle layer, which fills the surface voids and makes a close contact between the CuFeO₂ particles as shown in Fig. 2b and c. After 5 times of FeCl₃ gel spin-coating and annealing, a quite compact and smooth surface can be observed in Fig. 2d. Obviously, the surface morphology improved with the increasing of FeCl₃ gel spin-coating times. While 5 times is the optimal, after 6 times of spin-coating the surface of sample CFO-6 becomes cracked as shown in Fig. S1. This cracked surface structure impeded the stability of photoelectrode in aqueous electrolyte. The XRD pattern of the CFO-5 photoelectrode was measured and presented in Fig. S2, which shows the obvious diffraction peaks of well-crystallized CuFeO2 and α -Fe2O3 in good agreement with the standard JCPDS cards NO.01-075-2146 and 01-085-0599. And the

energy dispersive spectrometer (EDS) analysis for the cross section of the CFO-5 photoelectrode is also performed and presented in Fig. S3. Cu and Fe elements are dispersed throughout the film uniformly and the element content of Fe is a little bit higher than that of Cu. Considering these two element contents should be equal in pure CuFeO₂, it is reasonable to draw the conclusion that the Fe₂O₃ wraps the CuFeO₂ particles in the whole CFO-5 photoelectrode which leads to the higher Fe element content as shown in Fig. S3. There is no obvious Fe₂O₃ surface layer observable in Fig. 1d, with Fe₂O₃ uniformly distributed through the CFO-5 photoelectrode. Based on the above analysis, we draw the schematic model of CFO-5 photoelectrode as shown in Fig. S4. Notice here the Fe₂O₃ formed a thin buffer layer on the CuFeO₂ particle layer not a thick film. As the best performing catalyst for hydrogen evolved reaction (HER), Pt catalyst particles decoration has been proven to be effective to improve the PEC performance of the photoelectrodes. Here we fabricate the Pt catalyst particles on the surface of CFO-5 photoelectrode by photoreduction method (noted as CFO-5-Pt). The Pt particles are highly dispersed on the CFO-5-Pt surface with diameters of around 30 nm, as shown in SEM image of Fig. S5a. The EDS analysis of CFO-5-Pt surface in Fig. S5b further confirmed the uniform distribution of the Pt particles.

In Fig. 3a, we present the J-t curves of different photoelectrodes. There is no obvious photocurrent observed for CFO-0 and CFO-1 photoelectrodes. The CFO-3 photoelectrode exhibits a quite low photocurrent, which is due to the poor connection among CuFeO₂ particles and CuFeO₂/ITO glass interface, as we observed in Fig. 1. As for the CFO-5 photoelectrode, an obviously increased photocurrent, about $-95 \,\mu\text{A/cm}^2$, is observed, indicating that the Fe₂O₃ wrapped structure is crucial to the separation and transport of photo-generated electron-hole pairs. The photocurrent can be further enhanced to $-274 \,\mu\text{A/cm}^2$, after the Pt particles were decorated. Fig. 3b compares the J-V curves for CFO-5 photoelectrode before and after Pt particles decoration: the onset potentials (V_{op}) are 0.65 V and 0.87 V vs. Ag/ AgCl, respectively. Here we define Vop as the point where the cathodic photocurrent appears on J-V curves. Thus, the Pt particles decoration enhanced the Vop of the photoelectrode significantly, consistent with the enhancement of the photocurrent. Here, the dark photocurrent was not zero but changed with the applied potential. This phenomenon is very common in J-V testing which can be explained by the back reaction of conduction band electrons with holes trapped at the photoelectrode surface [10]. Electrochemical impedance spectroscopy (EIS) measurements were carried out to better understand the PEC performance of CFO-5 photoelectrode before and after Pt particles decoration.



Fig. 2. Top-down SEM images of (a) CFO-0, (b) CFO-1, (c) CFO-3 and (d) CFO-5.

The Nyquist impedance plot of two photoelectrodes show semicircles as presented in Fig. 3c. The semicircles of high frequency range on the left are nearly the same, indicating that they are originated from the ITO/ CFO interface. The second semicircles of low frequency range on the right change obviously after the decoration of Pt, indicating they are related to the front photoelectrode/electrolyte interface. As reported, the EIS data can be fitted to the different equivalent circuits [11]. The charge transfer resistance at ITO/CFO interface (R₁) indicated the coupling between the CFO and the ITO substrate. For CFO-5 photoelectrode before and after Pt decoration, R₁ are all around 261 Ω

illustrated the Pt decoration on surface do not change the back ITO/ CFO contact resistance. However, the total charge transfer resistance $R_4 = R_2 + R_3$ across the front photoelectrode/electrolyte interface changes significantly. R_4 reduces from 8654 Ω (R_2 equal to pure resistance at CFO/electrolyte interface in CFO-5 photoelectrode) to 4767 Ω (here R_2 represents resistance from CFO to Pt, R_3 represents resistance from Pt to electrolyte in CFO-5-Pt photoelectrode). Obviously, Pt decoration leads to the smaller diameters of the second circles, which correspond to smaller resistances for charge transfer at the photoelectrode/electrolyte interface and results in the improved



Fig. 3. (a) J–t and (b) J–V curves of different photoelectrodes, (c) EIS spectra and the solid traces correspond to the fitting curves of CFO-5 photoelectrode before and after Pt particles decoration, the insert is equivalent circuits and (d) UV–Vis absorption spectra of the CFO-5-Pt photoelectrode, the inset is the $(\alpha hv)^2 - (hv)$ plot.



Fig. 4. (a) Energy band structure of CFO-5-Pt photoelectrode and (b) hydrogen production vs. time and Faradic efficiency curves of the CFO-5-Pt photoelectrode. The nearly straight line is the theoretical values of hydrogen production calculated based on the electrons passing through the circuit.

PEC activity [12]. Fig. 3d is the UV–Vis absorption spectra of the CFO-5-Pt photoelectrode with a broad absorption below 830 nm. The corresponding energy band gap was estimated to be 1.35 eV from the inset $(\alpha hv)^2 - (hv)$ plot, which is in agreement with reference [13], indicates that CFO-5-Pt photoelectrode can absorb considerable amount of visible light, implying its potential application as visible light driven photocathode. Table S1 in Supporting information compared CFO-5-Pt photoelectrode with other reported p-type semiconductor photocathodes. As we can see, the CFO-5-Pt photoelectrode show good PEC performance.

CuFeO₂ has a suitable conduction band position for photoreducing water to hydrogen, and the Pt particles were proved to be one of the best HER catalysts [2]. The work function of Pt (5.64 eV) is much bigger than most of noble metal and $CuFeO_2$ [2]: as a result, an upward barrier will form at the CuFeO2/Pt interface if the Pt particles were decorated on CuFeO₂ surface directly. This barrier will impede the photo-generated electrons moving out from the photoelectrode surface to the electrolyte. Fe₂O₃ is an *n*-type semiconductor with good energy band matching with Pt [14,15]. Therefore, after the Fe₂O₃ buffer layer was inserted into the CuFeO2/Pt interface, the upward barrier was removed as illustrated in Fig. 4a. In addition, tunneling was also considered to be happening at the Fe₂O₃/Pt interface, since the Fe₂O₃ is very thin and highly conductive. As a result, the inserting of a Fe₂O₃ buffer layer removes the upward barrier and thus improves PEC activity. In addition to high efficiency, stability in aqueous electrolyte is also important for photoelectrode. We performed the long time stability test for CFO-5-Pt photoelectrode: for the good stability of Fe₂O₃ in electrolyte, a sustained photocurrent maintained at $-256 \,\mu\text{A/cm}^2$ was observed for up to 5 h continuous PEC reaction, as shown in Fig. S6. We believe that the Fe₂O₃ wrapped CuFeO₂ and as buffer layer structure significantly enhanced the attachment of CuFeO₂ particle layer, resulting in improved PEC stability. The time course of hydrogen production and water splitting Faradic efficiency of CFO-5-Pt photoelectrode were measured and shown in Fig. 4b. The water splitting reaction was conducted in 0.1 M Na₂SO₄ electrolyte solution with an Ag/AgCl reference electrode and a Pt mesh counter electrode. A 100 mW/cm² Xe lamp as light source and no bias was added between CFO-5-Pt photoelectrode and Pt electrode. After the beginning of water splitting reaction, hydrogen and oxygen bubbles were observed on the surface of CFO-5-Pt photoelectrode and Pt mesh respectively. The evolved hydrogen gas was collected and measured by gas chromatography and the photocurrent was recorded to calculate the Faradic efficiency for hydrogen production. The Faradic efficiency of hydrogen evolution was maintained above 87% over the 5 h continuous water splitting reaction. The Faradic efficiency was less than 100%, probably due to the unwanted backward reaction between hydrogen and oxygen [16].

4. Conclusions

In summary, we report a simple electrophoretic deposition and solgel route to fabricate a Fe₂O₃ wrapped CuFeO₂ layer structure photocathode on ITO glass substrate at 400 °C. The FeCl₃ gel fills up the voids among CuFeO₂ particles and enhanced the connection between CuFeO₂ particles layer and ITO glass substrate after annealing. The Fe₂O₃ also acts as a buffer layer at the CuFeO₂/Pt interface, inhibiting the formation of an upward barrier. As a result, a photocathodic current density of $-274 \,\mu$ A/cm² at 0 V vs. Ag/AgCl and an onset potential of 0.87 V vs. Ag/AgClwere obtained in 0.1 M Na₂SO₄ electrolyte under 100 mW/cm² Xe lamp illumination. The photocathode also shows high Faradic efficiency and stability after 5 h continuous water splitting testing. This study provides a new route to prepare CuFeO₂ as film photocathode on transparent substrate under low temperature and we propose that this work makes available a new pathway to the fabrication of delafossite compounds photoelectrodes under low temperature.

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Appendix A. Supplementary data

Supplementary data associated with this article can be found, in the online version, at https://doi.org/10.1016/j.chemphys.2018.08.009.

References

- [1] M. Woodhouse, B.A. Parkinson, Chem. Soc. Rev. 38 (2009) 197-210.
- M.S. Prévot, X.A. Jeanbourquin, W.S. Bourée, F. Abdi, D. Friedrich, R. van de Krol, N. Guijarro, F. Le Formal, K. Sivula, Chem. Mater. 29 (2017) 4952–4962.
 U. Kang, S.K. Choi, D.J. Ham, S.M. Ji, W. Choi, D.S. Han, A. Abdel-Wahab, H. Park.
- [3] U. Kang, S.K. Choi, D.J. Ham, S.M. Ji, W. Choi, D.S. Han, A. Abdel-Wahab, H. Park, Energy Environ. Sci. 8 (2015) 2638–2643.
 [4] A. Wuttig, J.W. Krizan, J. Gu, J.J. Frick, R.J. Cava, A.B. Bocarsly, J. Mater. Chem. A
- [1] A. Wutteg, J.W. Rizali, J. Gu, J.J. FICK, K.J. Cava, A.D. Docatsky, J. Water. Chem. 7 5 (2017) 165–171.
 [5] M.S. Prévot, N. Guiarro, K. Sivula, ChemSusChem 8 (2015) 1359–1367.
- [6] Y.J. Jang, Y.B. Park, H.E. Kim, Y.H. Choi, S.H. Choi, J.S. Lee, Chem. Mater. 28
- (2016) 6054–6061. [7] Y.J. Oh, W.S. Yang, J.M. Kim, S.H. Jeong, J.H. Moon, ACS Appl. Mater. Interfaces 9
- (2017) 14078–14087.
 [8] J.W. Lekse, M.K. Underwood, J.P. Lewis, C. Matranga, J. Phys. Chem. C 16 (2012)
- [9] A. Annamalai, A. Subramanian, U. Kang, H. Park, S.H. Choi, J.S. Jang, J. Phys.
- [9] A. Annamalai, A. Subramanian, U. Kang, H. Park, S.H. Choi, J.S. Jang, J. Phys. Chem. C 119 (2015) 3810–3817.

- [10] A. Hagfeldt, H. Lindström, S. Södergren, S. Lindquist, J. Electroanal. Chem. 381 (1995) 39–46.
- [11] Y.L. Huang, W.S. Chang, C.N. Van, H.J. Liu, K.A. Tsai, J.W. Chen, H.H. Kuo, W.Y. Tzeng, Y.C. Chen, C.L. Wu, C.W. Luo, Y.J. Hsu, Y.H. Chu, Nanoscale 8 (2016) 15795–15801.
- [12] T. Lopes, L. Andrade, H.A. Ribeiro, A. Mendes, Int. J. Hydrogen Energy 35 (2010) 11601–11608.
- [13] Y. Jin, G. Chumanov, RSC Adv. 6 (2016) 26392-26397.
- [14] G.M. Wang, Y.C. Ling, D.A. Wheeler, K.E.N. George, K. Horsley, C. Heske, J.Z. Zhang, Y. Li, Nano Lett. 11 (2011) 3503–3509.
- [15] P. Kumar, P. Sharma, R. Shrivastav, S. Dass, V.R. Satsangi, Int. J. Hydrogen Energy 36 (2011) 2777–2784.
- [16] E.S. Kim, N. Nishimaru, G. Magesh, J.Y. Kim, J.W. Jang, H. Jun, J. Kubota, K. Domen, J.S. Lee, J. Am. Chem. Soc. 135 (2013) 5375–5383.